Orthogonalized plane wave prethod
- In 10, we discussed expanding in a basis of plane
waves
- 30 generalization is straight forward:
H =
$$\frac{1}{p^2}$$
 + $\frac{1}{2}$ V, $(\vec{r} - \vec{s}_{r} - \vec{r}_{r})$
Leases vectors if composite lattice
* Basis functions: $W_{\vec{r}}(\vec{r}) = \frac{1}{|V||} e^{i(\vec{k} + \vec{h}_{r}) \cdot \vec{r}}$
* Matrix elements:
(WZ, |H| WZ) = $\frac{M^{+}K^{2}}{2m} \delta_{ij} + \frac{1}{N\Omega} \frac{2}{m} \delta_{ij} = -i(\vec{k} + \vec{h}_{r}) \cdot \vec{r}$
• Can write: Vy $(\vec{r} - \vec{d}_{y} - \vec{t}_{r}) = \frac{2}{3m} \tilde{V}_{y}(\vec{j}_{r}) \exp[i\vec{j}_{r} \cdot (\vec{r} - \vec{d}_{y} - \vec{t}_{r})]$
so matrix elements ave:
 $= \frac{2}{3m} \tilde{V}_{y}(\vec{j}_{r}) e^{i\vec{j}_{r} \cdot \vec{r}} e^{i\vec{j}_{r} \cdot \vec{r}}$
 $= \frac{M^{+}K^{2}}{2m} \delta_{ij} + \frac{1}{N\Omega} \frac{2}{m} \int \exp[i(\vec{k}_{s} - \vec{h}_{s} + \vec{j}_{r}) \cdot \vec{r}] \tilde{V}_{y}(\vec{j}_{r}) dr e^{-i\vec{j}_{r} \cdot \vec{d}_{r}}$
 $= \frac{1}{2} \tilde{V}_{y}(\vec{j}_{r}) e^{i\vec{j}_{r} \cdot \vec{r}} e^{i\vec{j}_{r} \cdot \vec{d}}$
 $= \frac{1}{2} \frac{M^{+}K^{2}}{2m} \delta_{ij} + \frac{1}{N\Omega} \frac{2}{m} \int \exp[i(\vec{k}_{s} - \vec{h}_{s} + \vec{j}_{r}) \cdot \vec{r}] \tilde{V}_{y}(\vec{j}_{r}) dr e^{-i\vec{j}_{r} \cdot \vec{d}_{r}}$
 $= \frac{1}{2} \tilde{V}_{x}(\vec{j}_{r}) e^{i\vec{j}_{r} \cdot \vec{r}} e^{i\vec{j}_{r} \cdot \vec{d}_{r}}$
 $= \frac{1}{2} \frac{M^{+}K^{2}}{2m} \delta_{ij} + \frac{1}{dy} e^{i(\vec{k}_{r} - \vec{h}_{r}) \cdot \vec{d}_{r}} V_{y}(\vec{k}_{r} - k_{r})$
 $= \frac{1}{2} \frac{M^{+}K^{2}}{2m} \delta_{ij} + \frac{2}{dy} e^{i(\vec{k}_{r} - \vec{h}_{r}) \cdot \vec{d}_{r}} V_{y}(\vec{k}_{r} - k_{r})$

At expand crystal Wavefunction at
$$\vec{k}$$
:
 $\Psi_{\vec{k}}(\vec{k}) = \sum_{i}^{N} C_{i\vec{k}} \quad \forall p (\vec{k})$
At solve secular equation:
 $det \left(\left[\frac{K_{i}^{2} + K^{2}}{2m} - E \right] \delta_{ij} + \sum_{ij}^{N} e^{-i(k_{i}-k_{j})} \cdot \vec{d}_{ij} \quad \forall_{ij} (\vec{k}_{i} - \vec{k}_{j}) \right| = 0$
But there is a problem with this method:
Treatment of core states requires way too many
place waxes!
At Why? Core states are very localized.
At Consider 1s state of Si:
 FCC lattice (w] basis) with $a = 10.26$ as (convention cell)
 \Rightarrow primitive cell volume is $SL = a_{ij}^{2}$
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 $FCC = 0$ succers $A = 0$

- How can we avoid this issue? In any case, we are most interested in properties of valence electrons, not core.

* Solution:

- Assume we know the form of the core states, i.e.,
 they remain atomic like (tight binding picture)
- Obtain a new basis that is ofthogonalized WRT the core orbitals
- * Or thogonalization:
 - · Assume we know the first he eigenfuctions of H:

$$H \Psi_{c} = F_{c} \Psi_{c} , c = 1, 2, \dots, N_{c}$$

· For any <u>basis</u> state Φ_i , consider an orthogonalized version Φ_i :

$$|\phi_i\rangle = |\phi_i\rangle - \frac{2}{2}|\psi_c\rangle < \psi_c|\phi_i\rangle$$

- Then we can expand any state "above" h_c as $|\Psi_i \rangle = \underbrace{\forall}_{ij} [\widehat{\Phi}_j \rangle$, $i \neq 1, 2, ..., n_c$
- Thus to get 4i's and Ei's, solve secular equation: $det[\langle \tilde{\varphi}_i | H | \tilde{\varphi}_j \rangle - E \langle \tilde{\varphi}_i | \tilde{\varphi}_j \rangle] = 0$ $\sim not orthogonal!!$

 $\Rightarrow cet | \langle \tilde{\Phi}_{i} \rangle | = 0$ $\langle \tilde{\Phi}_{i} | H - E[\tilde{\Phi}_{j} \rangle - \langle \phi_{i} \rangle | H - E[\tilde{Z}_{i} | \Psi_{c} \rangle \langle \Psi_{c} | \Phi_{j} \rangle]$ $- [\tilde{Z}_{i} \langle \phi_{i} \rangle | \Psi_{c} \rangle \langle \Psi_{c} |] H - E[\Phi_{j} \rangle$ $+ \frac{Z}{cc'} \langle \phi_{i} | \Psi_{c} \rangle \langle \Psi_{c} | H - E[\Psi_{c'} \rangle \langle \Psi_{c'} | \Phi_{j} \rangle$

$$= \langle \phi_{c} | H - E | \phi_{j} \rangle - \langle \phi_{c} | \begin{bmatrix} \xi' (E_{c} - E) | H_{c} \rangle \langle \mathcal{U}_{c} | \end{bmatrix} | \phi_{j} \rangle$$

$$= \langle \phi_{c} | \begin{bmatrix} \xi' (E_{c} - E) | \mathcal{U}_{c} \rangle \langle \mathcal{U}_{c} | \end{bmatrix} | \phi_{j} \rangle \int_{c} cancels \text{ one } \rho_{rev.}$$

$$= \langle \phi_{c} | \begin{bmatrix} \xi' (E_{c} - E) | \mathcal{U}_{c} \rangle \langle \mathcal{U}_{c} | \mathcal{U}_{c} \rangle \langle \mathcal{U}_{c} | \end{bmatrix} | \phi_{j} \rangle \int_{c} cancels \text{ one } \rho_{rev.}$$

$$= \langle \varphi_{c} | \left[H - E + \frac{1}{2} (E - E_{c}) | \Psi_{c} \rangle \langle \Psi_{c} | \right] | \varphi_{j} \rangle$$

Urep

• So we can write the secular equation in terms of
original basis functions:
$$det |\langle \varphi_i| H + V^{rep} | \varphi_j \rangle - E \delta_{ij} | = 0$$

• Note that eigenveriois of gives coeff of
$$|\Psi_i\rangle = Z_{ij}|\Phi_j\rangle$$

- Vrep for E? Ec is a repulsive potential, increases energy above core states
- Note vrep is a nonlocal potential! I.e., in position basis:

$$\langle r | v^{rep} | r' \rangle = 2 (E - E_c) 4(r) 4(r') = V^{rep} (r, r') \neq v^{rep} (r) \delta(r-r')$$

$$|\widetilde{W}\vec{k}_{j}\rangle = |\widetilde{W}\vec{k}_{j}\rangle - \stackrel{{}_{\sim}}{\underset{core}{2}} |\overline{\Phi}\vec{k}_{i}\rangle \langle \overline{\Phi}\vec{k}_{i}\rangle |\widetilde{W}\vec{k}_{j}\rangle$$

• Then we have:

$$\frac{1}{\sqrt{12}} = \frac{1}{\sqrt{12}} = \frac{1}{\sqrt{12}}$$

Similar Spirit of Combining plane waves for itinerant Valence / conduction electrons with radial/atomic functions for core states <u>Pseudopotential</u> method

- OPW allows us to separate "inert" core from valence states [or unoccupied "conduction" states)
- Problem: we still have to deal with the full Crystal potential VIN

* Atomic - like so strong in the core region

- * Also, Valence electron vave functions will have oscillations in core region since they need to be of thogonal to core
- Solution: replace crystal potential in Ore region with a weaker "pseudopotential"
 - * Eigenstates will be "pseudo wavefunctions," only required to match the wavefunctions outside of core region
 - * We kind of did this w/ OPW, Vrep cancels some of VLP) in the core region * replace V+Vrep with V^{PSP} : $det \left[\left(\frac{\hbar^2 k_i^2}{2m} - E \right) \delta_{ij} + \frac{2}{dp} e^{-i(\vec{h}_i - \vec{h}_j) \cdot \vec{d}v} V_{v}^{PSP} (\vec{h}_i - \vec{h}_j) \right] = 0$
 - of Can often choose V^{ASP} to have few Fourier components
 - Example in G and P sec. U.4 (and HW ::):
 band structure of Si with just three
 parameters and ~40 reciprocal lattice vectors

- How do we determine
$$V^{PSP}$$
?
* Empirical pseudopotentials: fit to experiment of other
calculations (S: example)
* Atomic/ab-initio pseudopotentials: Calculate U of free atom,
take exact U outside of Tadius Tc from core,
use approximate (weak) form inside of Tc
• Simplest form: $V^{PSP}(t) = \int A$ for $T \ge T_c$
• Another prescription: Parametrize Tadial pseudowavefunctions
as: $P^{PSP}(t) = \int r^2 e^{P(t)}$ for $T \ge T_c$
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as: $P^{PSP}(t) = \int r^2 e^{P(t)}$ for $T \ge T_c$
where $p(t) = 2o + 2z t^2 + 2z t^3 + 2y t^4$
 $Plug into Tadial S. E. to get:
 $V^{PSP}(t) = \int E^a + 2\frac{L+1}{T} p^1(t) + p^1(t) + [p^1(t)]^2$ for $t \ge T_c$
• Choose 2's so wavefunction is normalized to 1 to$

- conserve charge in core region, and R(12) and derivatives are continuous
- · Note: R^{psp} has no nodes:



• Note: V^{PSP} is different for different angular momentum. In practice, it will have a nonlocal part of the form VPSD = St | Quen > 2 Quen | 5 Nor 9 6 **C**c

- Most popular modern "ab initio" treatment of Solids use plane waves and pseudopotentials! Methods for describing bands in 3D what have we learned?

- Can describe bands in 3D enpirically with relatively fer free parameters
- Tight binding: Make Bloch sums for different types of orbitals, parametrize matrix elements based on orbital type and direction
 - * Often most convenient for (semi) analytical description OF solids
- plane wave expansion: Have to combine localized atomic like functions for core electrons with itinerant plane waves
 - + often most convenient for full numerical treatment of solids